

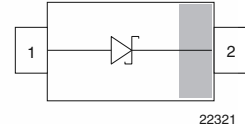
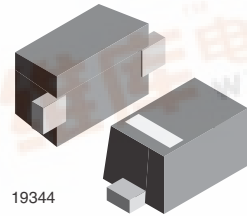
## Small Signal Schottky Diode

### Features

- This diode features very low turn-on voltage and fast switching
- This device is protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges
- Space saving SOD-523 package
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC



RoHS  
COMPLIANT  
GREEN  
(5-2008)\*\*



### Mechanical Data

**Case:** SOD-523

**Weight:** approx. 1.4 mg

**Molding compound flammability rating:**

UL 94 V-0

**Terminals:** high temperature soldering guaranteed:  
260 °C/10 s at terminals

**Packaging codes/options:**

08/3K per 7" reel (8 mm tape), 15K/box

### Parts Table

Part	Ordering code	Type marking	Remarks
BAS40-02V-V-G	BAS40-02V-V-G-08	.W	Tape and reel

### Absolute Maximum Ratings

$T_{amb} = 25\text{ °C}$ , unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Repetitive peak reverse voltage		$V_{RRM}$	40	V
Forward continuous current		$I_F$	120	mA
Surge forward current		$I_{FSM}$	600	mA
Power dissipation		$P_{tot}$	150	mW

### Thermal Characteristics

$T_{amb} = 25\text{ °C}$ , unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air		$R_{thJA}$	680	K/W
Junction temperature		$T_j$	125	°C
Storage temperature range		$T_{stg}$	- 55 to +150	°C

\*\* Please see document "Vishay Material Category Policy": [www.vishay.com/doc?99902](http://www.vishay.com/doc?99902)

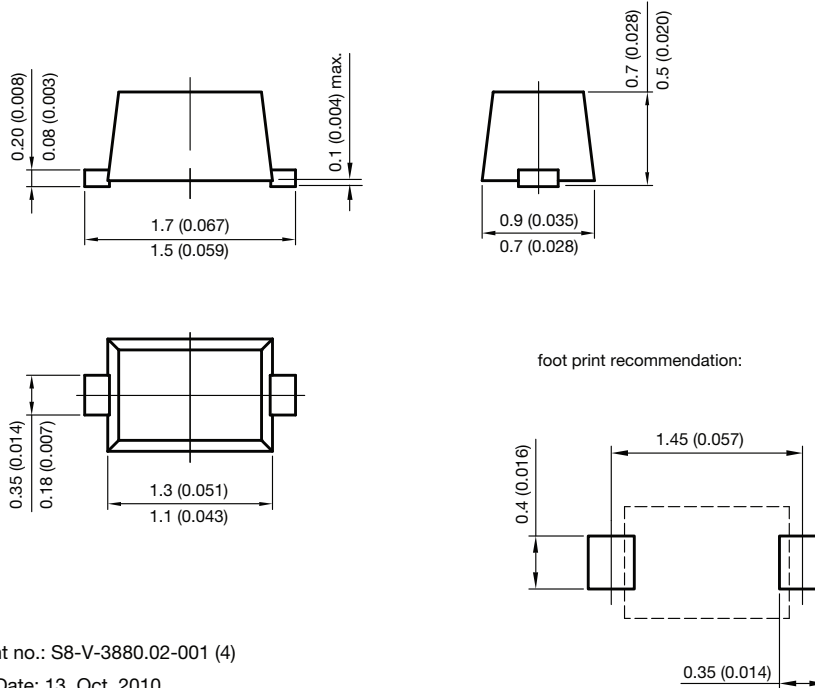


## Electrical Characteristics

T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min.	Typ.	Max.	Unit
Reverse breakdown voltage	I <sub>R</sub> = 10 μA (pulsed)	V <sub>(BR)</sub>	40			V
Leakage current	Pulse test V <sub>R</sub> = 30 V, t <sub>p</sub> < 300 μs	I <sub>R</sub>		20	100	nA
Forward voltage	Pulse test t <sub>p</sub> < 300 μs, I <sub>F</sub> = 1 mA	V <sub>F</sub>			380	mV
	Pulse test t <sub>p</sub> < 300 μs, I <sub>F</sub> = 40 mA,	V <sub>F</sub>			1000	mV
Diode capacitance	V <sub>R</sub> = 0 V, f = 1 MHz	C <sub>D</sub>		4	5	pF
Reverse recovery time	I <sub>F</sub> = 10 mA, I <sub>R</sub> = 10 mA, I <sub>rr</sub> = 1 mA, R <sub>L</sub> = 100 Ω	t <sub>rr</sub>			5	ns

## Package Dimensions in millimeters (inches): SOD-523



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## Disclaimer

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